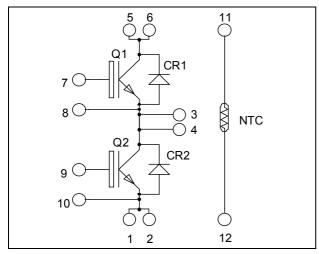
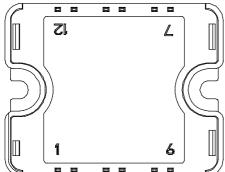


Phase leg Trench + Field Stop IGBT3 Power Module







Pins 1/2; 3/4; 5/6 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
 - Very low stray inductance
 - Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1700	V
La Continuous Collector Current	Continuous Collector Current	$T_C = 25^{\circ}C$	75	
	$T_C = 80^{\circ}C$	50	Α	
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	100	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25^{\circ}C$	312	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	100A @ 1600V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1700V$				250	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		2.0	2.4	V
V CE(sat)	Confector Emitter Saturation Voltage	$I_C = 50A$ $T_j = 125^{\circ}C$		2.4		V	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 1 \text{mA}$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$			4400		
C_{oes}	Output Capacitance				180		pF
C_{res}	Reverse Transfer Capacitance				150		
$T_{d(on)}$	Turn-on Delay Time	Inductive Swite	ching (25°C)		370		
T_{r}	Rise Time	$V_{GE} = 15V$			40		ns
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 900V$ $I_{\text{C}} = 50A$			650		
$T_{\rm f}$	Fall Time	$R_G = 10\Omega$			180		i
$T_{d(on)}$	Turn-on Delay Time	Inductive Swite	ching (125°C)		400		
T_{r}	Rise Time	$V_{GE} = 15V$			50		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 900V$ $I_{C} = 50A$			800		ns
T_{f}	Fall Time	$R_G = 10\Omega$			300		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 900V$	$T_j = 125$ °C		16		I en
E_{off}	Turn-off Switching Energy	$I_C = 50A$ $R_G = 10\Omega$	$T_j = 125$ °C		15		mJ

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1700			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1700V	$T_j = 25^{\circ}C$			250	μA
1 _{RM}		V _R -1700 V	$T_j = 125$ °C			500	μΛ
I_F	DC Forward Current		$Tc = 80^{\circ}C$		50		A
$V_{\rm F}$	Diode Forward Voltage	$I_F = 50A$	$T_j = 25^{\circ}C$		1.8	2.2	V
* F	Blode Forward Voluge		$T_{i} = 125^{\circ}C$		1.9		*
t _{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$		385		ns
ι _{rr}	Reverse Recovery Time		$T_{j} = 125^{\circ}C$		490		113
0	Reverse Recovery Charge	$I_F = 50A$ $V_R = 900V$ $di/dt = 800A/\mu s$	$T_j = 25^{\circ}C$		14		μС
Q_{rr}	Reverse Recovery Charge		$T_{\rm j} = 125^{\circ}{\rm C}$		23		μ
Е	Reverse Recovery Energy	Т	$T_j = 25$ °C		6		mJ
E _r			$T_{i} = 125^{\circ}C$		12		1113



Thermal and package characteristics

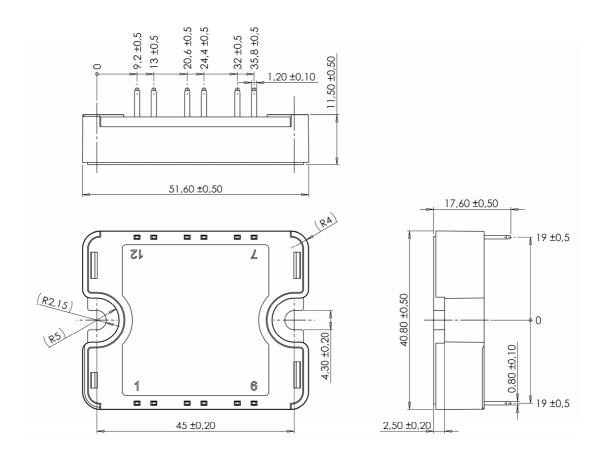
Symbol	Characteristic			Min	Тур	Max	Unit
D	Junction to Case Thermal Resistance		IGBT Diode			0.40	°C/W
R_{thJC}	Junction to Case Thermal Resistance				0.70	C/ VV	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature					100	
Torque	Mounting torque	To heatsink	M4	2	·	3	N.m
Wt	Package Weight				80	g	

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Typ	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature } \\ R_{T}: \text{ Thermistor value at T}$$

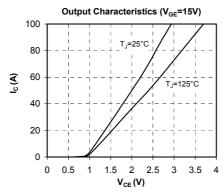
SP1 Package outline (dimensions in mm)

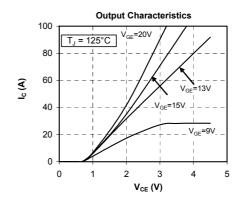


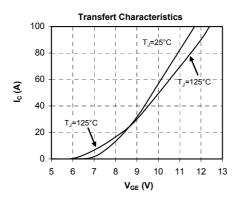
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

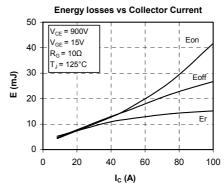


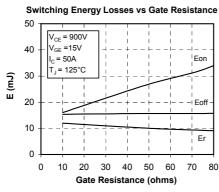
Typical Performance Curve

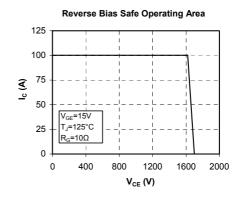


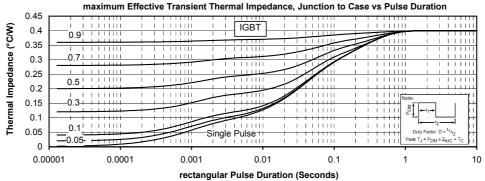




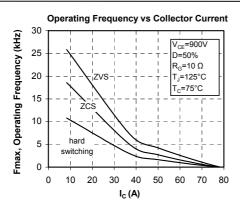


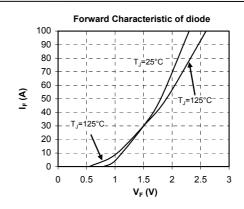


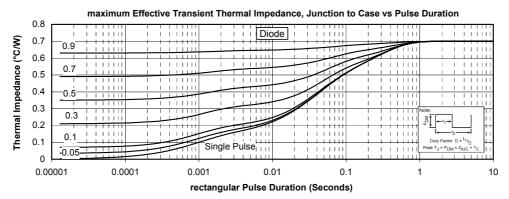














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